

Docket No.: 204552033800
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of:
Robert DWILINSKI et al.

Confirmation No.: 4375

Patent No.: 7,589,358

Issued: September 15, 2009

For: PHOSPHOR SINGLE CRYSTAL SUBSTRATE
AND METHOD FOR PREPARING THE
SAME, AND NITRIDE SEMICONDUCTOR
DEVICE USING THE SAME

REQUEST FOR CERTIFICATE OF CORRECTION
PURSUANT TO 37 CFR 1.322

Attention: Certificate of Correction Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Upon reviewing the above-identified patent, Patentees noted a typographical error which should be corrected.

On the front page, the Title (54) should read as follows:

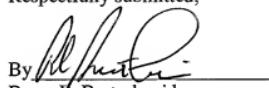
PHOSPHOR SINGLE CRYSTAL SUBSTRATE AND METHOD FOR PREPARING
THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING THE SAME

The error was not in the application as filed by applicant; accordingly no fee is required.

Transmitted herewith is a proposed Certificate of Correction effecting such amendment.
Patentee respectfully solicits the granting of the requested Certificate of Correction.

Dated: October 19, 2009

Respectfully submitted,

By 
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UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

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PATENT NO. : 7,589,358
APPLICATION NO. : 10/514,429
ISSUE DATE : September 15, 2009
INVENTOR(S) : Robert DWILINSKI et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the front page, the Title (54) should read as follows:

PHOSPHOR SINGLE CRYSTAL SUBSTRATE AND METHOD FOR
PREPARING THE SAME, AND NITRIDE SEMICONDUCTOR DEVICE USING THE
SAME

MAILING ADDRESS OF SENDER (Please do not use customer number below):

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